MOSFETs Silicon N-Channel MOS (DTMOS II )

# TK50J60U

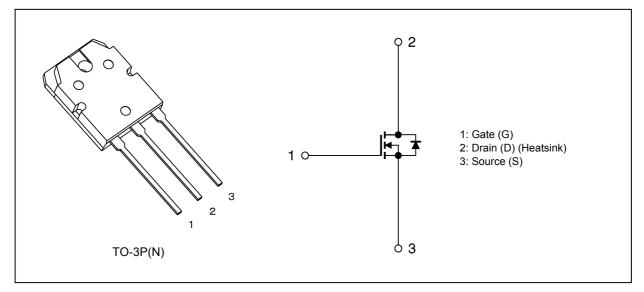
#### 1. Applications

• Switching Voltage Regulators

#### 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 0.056 \Omega$  (typ.)
- (2) High forward transfer admittance:  $|Y_{fs}| = 30 \text{ S}$  (typ.)
- (3) Low leakage current:  $I_{DSS}$  = 100  $\mu$ A (max) ( $V_{DS}$  = 600 V)
- (4) Enhancement mode:  $V_{\rm th}$  = 3.0 to 5.0 V (V\_{\rm DS} = 10 V,  $I_{\rm D}$  = 1 mA)

#### 3. Packaging and Internal Circuit



### 4. Absolute Maximum Ratings (Note) ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit	
Drain-source voltage		V <sub>DSS</sub>	600	V
Gate-source voltage		V <sub>GSS</sub>	±30	
Drain current (DC)	(Note 1)	Ι <sub>D</sub>	50	A
Drain current (pulsed)	(Note 1)	I <sub>DP</sub>	100	
Power dissipation $(T_c = 25^{\circ}C)$		PD	400	W
Single-pulse avalanche energy	(Note 2)	E <sub>AS</sub>	900	mJ
Avalanche current		I <sub>AR</sub>	25	A
Repetitive avalanche energy	(Note 3)	E <sub>AR</sub>	40	mJ
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R <sub>th(ch-c)</sub>	0.313	°C/W
Channel-to-ambient thermal resistance	R <sub>th(ch-a)</sub>	50	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V<sub>DD</sub> = 90 V, T<sub>ch</sub> = 25°C (initial), L = 2.52 mH, R<sub>G</sub> = 25  $\Omega$ , I<sub>AR</sub> = 25 A

Note 3: Repetitive rating; pulse width limited by maximum channel temperature

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

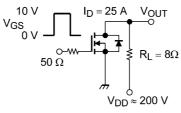
#### 6. Electrical Characteristics

#### 6.1. Static Characteristics (Ta = 25°C unless otherwise specified)

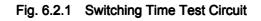
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±30 V, $V_{DS}$ = 0 V	_	_	±1	μA
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V	_		100	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	600	—	—	V
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	3.0	_	5.0	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 25 A	_	0.056	0.065	Ω
Forward transfer admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 25 A	7.5	30	_	S

### 6.2. Dynamic Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V, f = 100 kHz	_	4050	—	pF
Reverse transfer capacitance	C <sub>rss</sub>		_	2	—	
Output capacitance	C <sub>oss</sub>		_	210	—	
Switching time (rise time)	t <sub>r</sub>	See Figure 6.2.1.	_	90	_	ns
Switching time (turn-on time)	t <sub>on</sub>		_	200	—	
Switching time (fall time)	t <sub>f</sub>		_	17	—	
Switching time (turn-off time)	t <sub>off</sub>		_	200	_	



Duty  $\leq$  1%, t<sub>w</sub> = 10  $\mu$ s



#### 6.3. Gate Charge Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD}\approx 400 \text{ V},  V_{GS} \text{ = } 10  \text{V},  \text{I}_{D} \text{ = } 50  \text{A}$	_	67	—	nC
Gate-source charge	Q <sub>gs</sub>		_	45	_	
Gate-drain charge	Q <sub>gd</sub>		_	22	_	

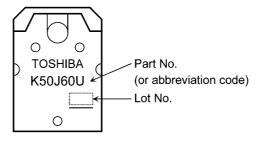
#### 6.4. Source-Drain Characteristics (Ta = 25°C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (DC)	(Note 1)	I <sub>DR</sub>	—	_	_	50	A
Reverse drain current (pulsed)	(Note 1)	I <sub>DRP</sub>	—	_	—	100	
Diode forward voltage		V <sub>DSF</sub>	I <sub>DR</sub> = 50 A, V <sub>GS</sub> = 0 V	—	—	-1.7	V
Reverse recovery time		t <sub>rr</sub>	I <sub>DR</sub> = 50 A, V <sub>GS</sub> = 0 V	_	600	_	ns
Reverse recovery charge		Q <sub>rr</sub>	-dI <sub>DR</sub> /dt = 100 A/μs	_	17	_	μC

### TK50J60U

# TOSHIBA

#### 7. Marking (Note)



#### Fig. 7.1 Marking

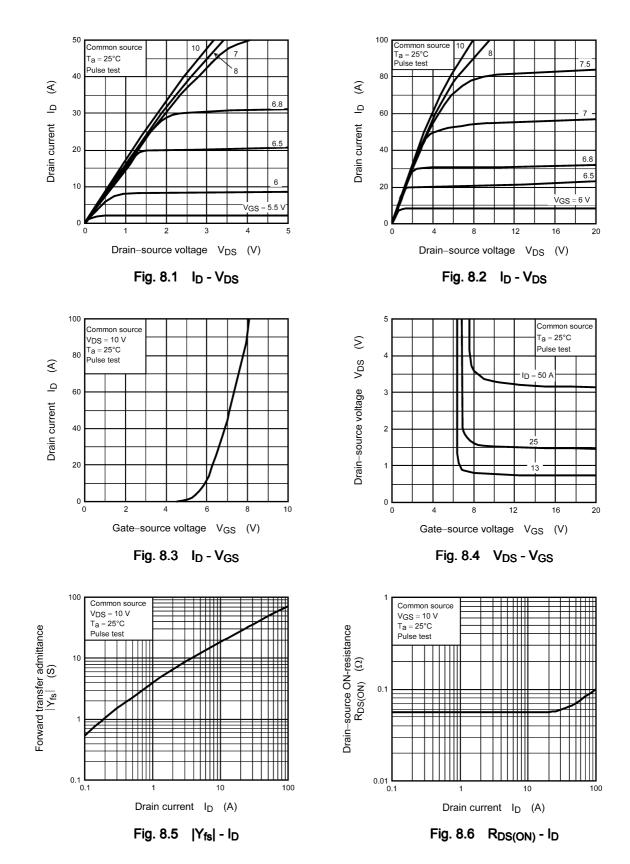
Note: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV

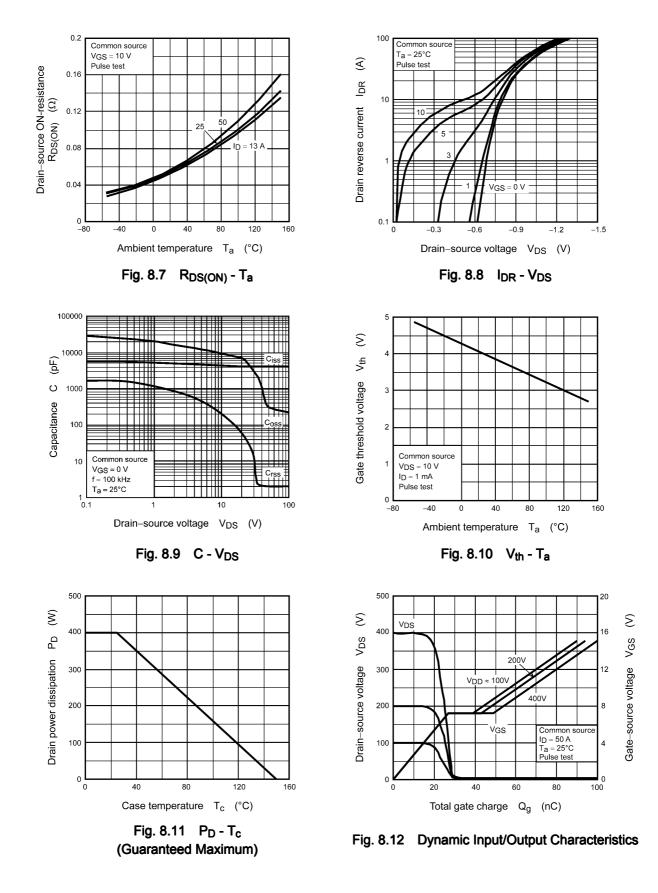
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

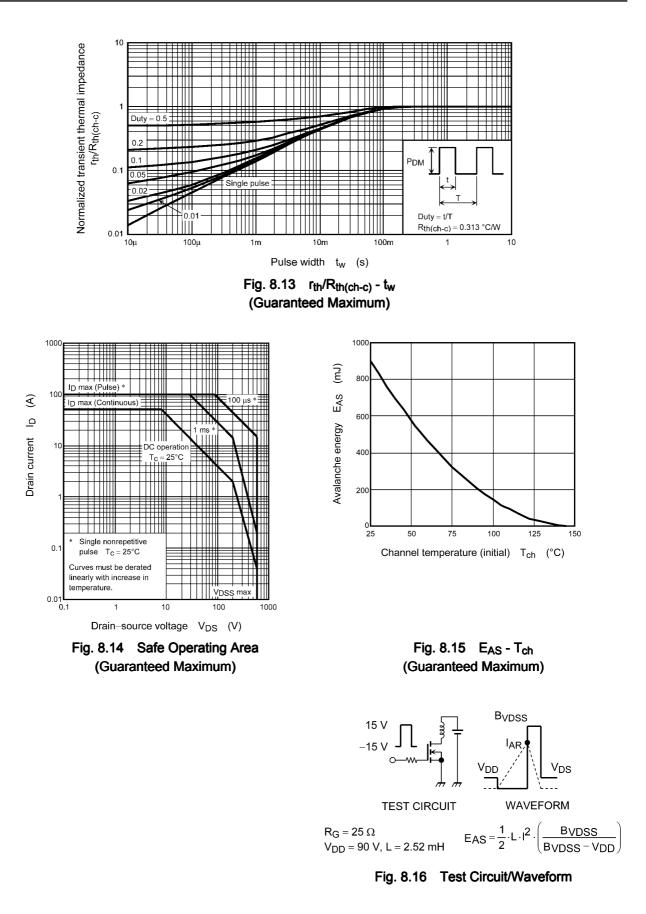
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

#### 8. Characteristics Curves (Note)





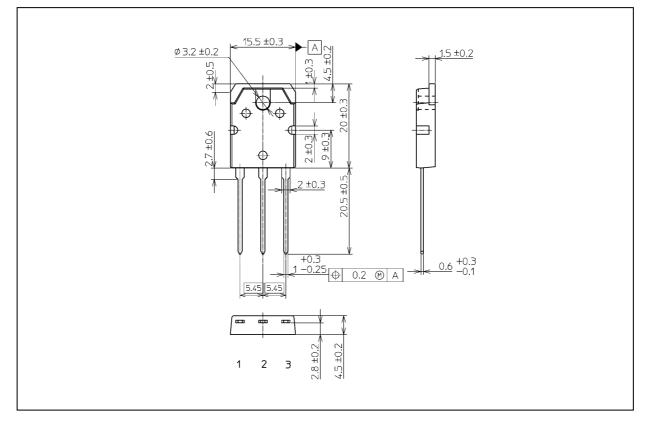


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

### TK50J60U

### Package Dimensions

Unit: mm



#### Weight: 4.6 g (typ.)

Package Name(s)
JEITA: SC-65
TOSHIBA: 2-16C1S
Nickname: TO-3P(N)

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